

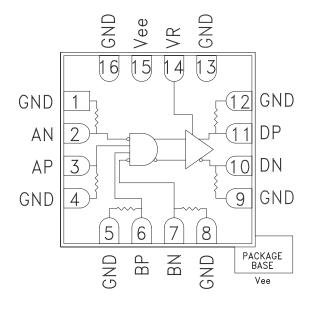


Typical Applications

The HMC672LC3C is ideal for:

- RF ATE Applications
- Broadband Test & Measurement
- Serial Data Transmission up to 13 Gbps
- Digital Logic Systems up to 13 GHz
- NRZ-to-RZ Conversion

Functional Diagram



Features

Supports High Data Rates: up to 13 Gbps Differential & Singe-Ended Operation Fast Rise and Fall Times: 24 / 22 ps Low Power Consumption: 180 mW typ.

Programmable Differential

Output Voltage Swing: 400 - 1100 mV

Propagation Delay: 60 ps Single Supply: -3.3 V

16 Lead Ceramic 3x3mm SMT Package: 9mm²

General Description

The HMC672LC3C is a AND/NAND/OR/NOR function designed to support data transmission rates of up to 13 Gbps, and clock frequencies as high as 13 GHz. The HMC672LC3C may be easily configured to provide any of the following logic functions: AND, NAND, OR and NOR. All input signals to the HMC672LC3C are terminated with 50 Ohms to ground on-chip, and maybe either AC or DC coupled. The differential outputs of the HMC671LC3C may be either AC or DC coupled. Outputs can be connected directly to a 50 Ohm to ground terminated system, while DC blocking capacitors may be used if the terminating system is 50 Ohms to a non-ground DC voltage. The HMC672LC3C operates from a single -3.3V DC supply, dissipates only 180 mW, and is available in a ceramic RoHS compliant 3x3 mm SMT package.

Electrical Specifications, $T_A = +25$ °C, Vee = -3.3V

Parameter	Conditions	Min.	Тур.	Max	Units
Power Supply Voltage		-3.6	-3.3	-3.0	V
Power Supply Current			55		mA
Maximum Data Rate			13		Gbps
Maximum Clock Rate			13		GHz
Clock Bandwidth, 3 dB	200 mVpp Input		12.2		GHz
Input High Voltage		-0.5		0.5	V
Input Low Voltage		-1.0		0.0	V
Input Return Loss	Frequency <13 GHz		10		dB
Output Amplitude	Single-Ended, peak-to-peak		550		mVpp
	Differential, peak-to-peak		1100		mVpp
Output High Voltage			-10		mV
Output Low Voltage			-570		mV



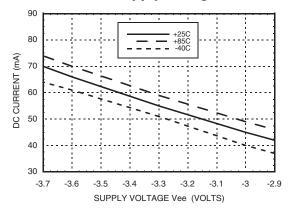


Electrical Specifications, (continued)

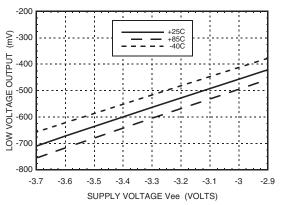
Parameter	Conditions	Min.	Тур.	Max	Units
Output Rise / Fall Time	Differential, 20% - 80%		24 / 22		ps
Output Return Loss	Frequency <13 GHz		10		dB
Small Signal Gain			27		dB
Random Jitter Jr	rms ^[1]			0.2	ps rms
Deterministic Jitter, Jd	peak-to-peak, 2 ¹⁵ -1 PRBS input [2]		2		ps, pp
Propagation Delay, td			60		ps
Off Isolation	Conditions:<13GHz, Port B=Low Voltage		50		dB

^[1] Upper limit of random jitter, JR, determined by measuring and integrating output phase noise with a sinusodal input at 5, 10, and 13.5 GHz over temperature

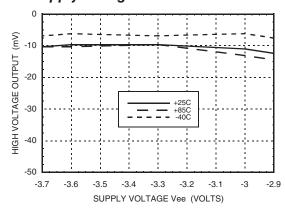
DC Current vs. Supply Voltage [1]



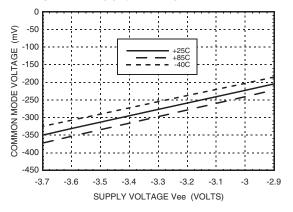
Output Low Voltage vs. Supply Voltage [1] [2]



Output High Voltage vs. Supply Voltage [1] [2]



Common Mode Voltage [1] [2]



[1] VR = 0.0V

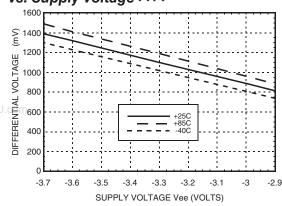
[2] Frequency = 1 GHz

^[2] Deterministic jitter calculated by simultaneously measuring the jitter of a 200 mV, 12.5 GHz, 215-1 PRBS input, and a single-ended output

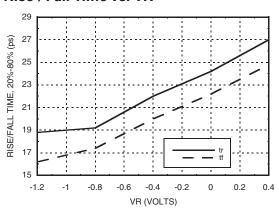




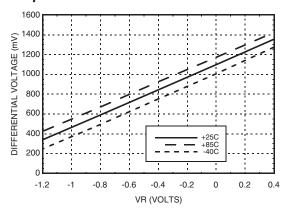
Output Differential vs. Supply Voltage [1] [2]



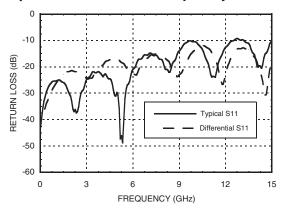
Rise / Fall Time vs. VR [3]



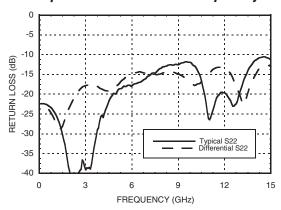
Output Differential vs. VR [2]



Input Return Loss vs. Frequency



Output Return Loss vs. Frequency



[1] VR = 0.0V

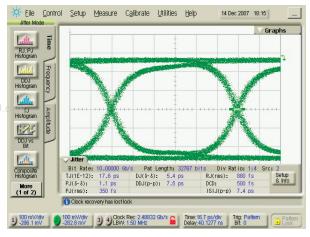
[2] Frequency = 1 GHz

[3] Frequency = 5 GHz





Eye Diagram



[1] Test Conditions:

Pattern generated with an Agilent N4901B Serial BERT

Eye diagram data presented on an Infinium DCA 86100A

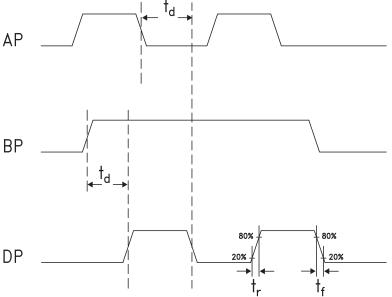
Rate = 10.0 GB/s

Pseudo Random Code = 2¹⁵ -1

Vin = 400 mVpp differential

[2] Vertical Scale = 100 mV/Div

Timing Diagram



Truth Table

Input		Outputs	
A	В	D	
L	L	L	
L	Н	L	
Н	L	L	
Н	Н	Н	
Notes: A = AP - AN B = BP - BN D = DP - DN	H - Negative voltage level L - Positive voltage level		





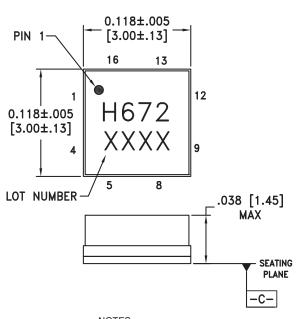
Absolute Maximum Ratings

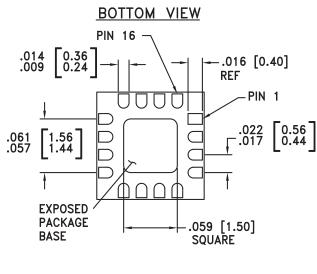
Power Supply Voltage (Vee)	-3.75V to +0.5V	
Input Signals	-2V to +0.5V	
Output Signals	-1.5V to +1V	
Storage Temperature	-65°C to +150°C	
Operating Temperature	-40°C to +85°C	



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Outline Drawing





NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING:
- 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
- 7. GROUND PADDLE MUST BE SOLDERED TO Vee.

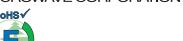




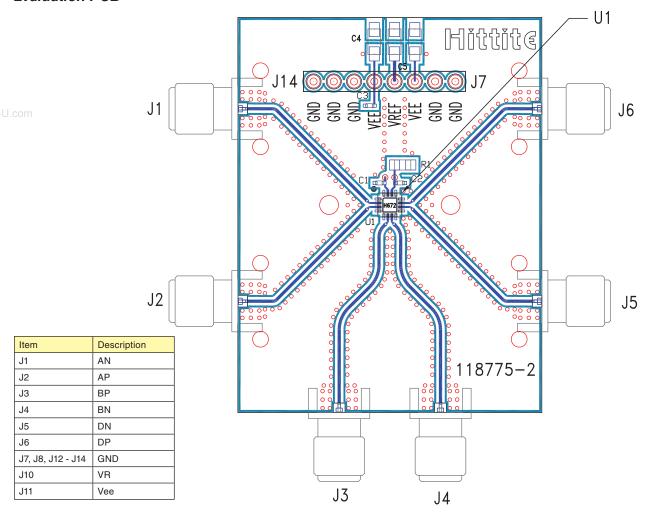
Pin Descriptions

	Pin Number	Function	Description	Interface Schematic
	1, 4, 5, 8, 9, 12	GND	Signal Grounds	GND =
J.0	com 2, 3	AN, AP	Clock / Data Input A	GND 500 AP, AN
	6, 7	BP, BN	Clock / Data Input B	GND 500 BP, BN
	10, 11	DN, DP	Clock / Data Output	GND 500 DP, DN
	13, 16	GND	Supply Ground	GND =
	14	VR	Output level control. Output level may be adjusted by either applying a voltage to VR per "Output Differenital vs. VR" plot, or by tying VR to GND with a resister per the following equation: $V_0(R) = 1.2 / (2.1 + R)$, R in k Ω	VR 0
	15, Package Base	Vee	Negative Supply	





Evaluation PCB



List of Materials for Evaluation PCB 118777 [1]

Item	Description
J1 - J6	PCB Mount SMA RF Connectors
J7 - J14	DC Pin
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4 - C5	4.7 μF Capacitor, Tantalum
R1	10 Ohm Resistor, 0603 Pkg.
U1	HMC672LC3C High Speed Logic, AND / NAND / OR / NOR
PCB [2]	118775 Evaluation Board

^[1] Reference this number when ordering complete evaluation $\ensuremath{\mathsf{PCB}}$

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. The exposed package base should be connected to Vee. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350





Application Circuit

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